

## 1. General description

High voltage, high speed, planar passivated NPN power switching transistor with integrated anti-parallel E-C diode in a SOT78 (TO-220AB) plastic package.

## 2. Features and benefits

- Low thermal resistance
- Fast switching
- High voltage capability
- Integrated anti-parallel E-C diode

## 3. Applications

- Integrated fluorescent lamp ballasts e.g. high power cluster lamps
- Low Voltage Tungsten Halogen transformers
- Remote fluorescent lamp ballasts
- Self Oscillating Power Supplies

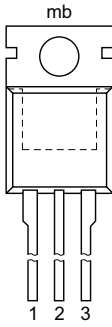
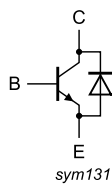
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit
<b>Absolute maximum rating</b>						
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0 \text{ V}$	700			V
$I_C$	collector current	DC; <a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 4</a>	4			A
$P_{tot}$	total power dissipation	$T_{mb} \leq 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 3</a>	75			W
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$h_{FE}$	DC current gain	$I_C = 1.0 \text{ A}$ ; $V_{CE} = 5 \text{ V}$ ; <a href="#">Fig. 10</a>	12	20	40	
		$I_C = 2.0 \text{ A}$ ; $V_{CE} = 5 \text{ V}$ ; <a href="#">Fig. 10</a>	10	17	28	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base		
2	C	collector		
3	E	emitter		
mb	C	mounting base; connected to collector		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PHD13005	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

## 7. Limiting values

**Table 4. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Values	Unit
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	700	V
$V_{CBO}$	collector-base voltage	$I_E = 0\text{ A}$	700	V
$V_{CEO}$	collector-emitter voltage	$I_B = 0\text{ A}$	400	V
$I_C$	collector current	DC; <a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 4</a>	4	A
$I_{CM}$	peak collector current	<a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 4</a>	8	A
$I_B$	base current	DC	2	A
$I_{BM}$	peak base current		4	A
$P_{tot}$	total power dissipation	$T_{mb} \leq 25\text{ °C}$ ; <a href="#">Fig. 3</a>	75	W
$T_{stg}$	storage temperature		-65 to 150	°C
$T_j$	junction temperature		150	°C

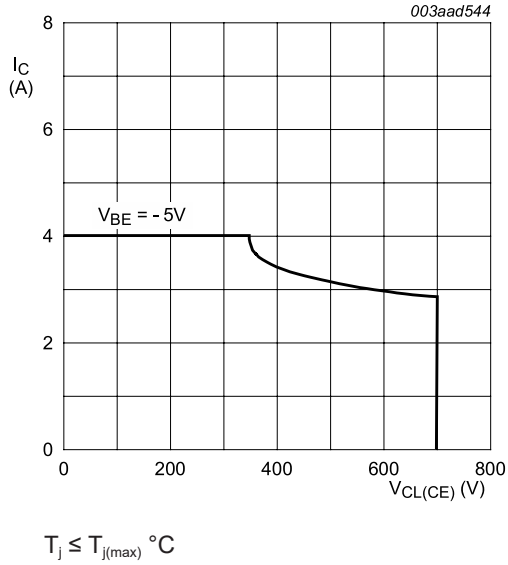
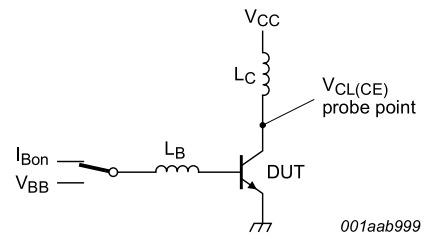
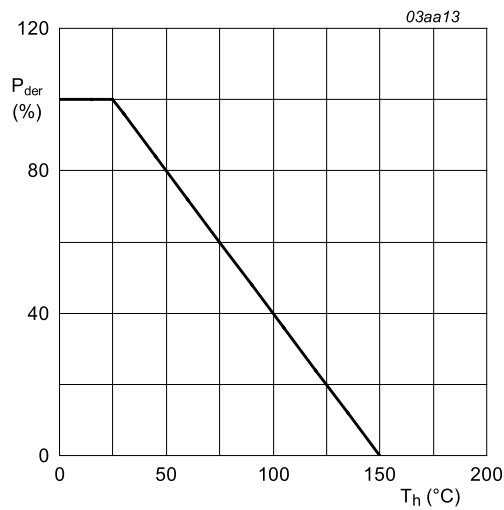


Fig. 1. Reverse bias safe operating area



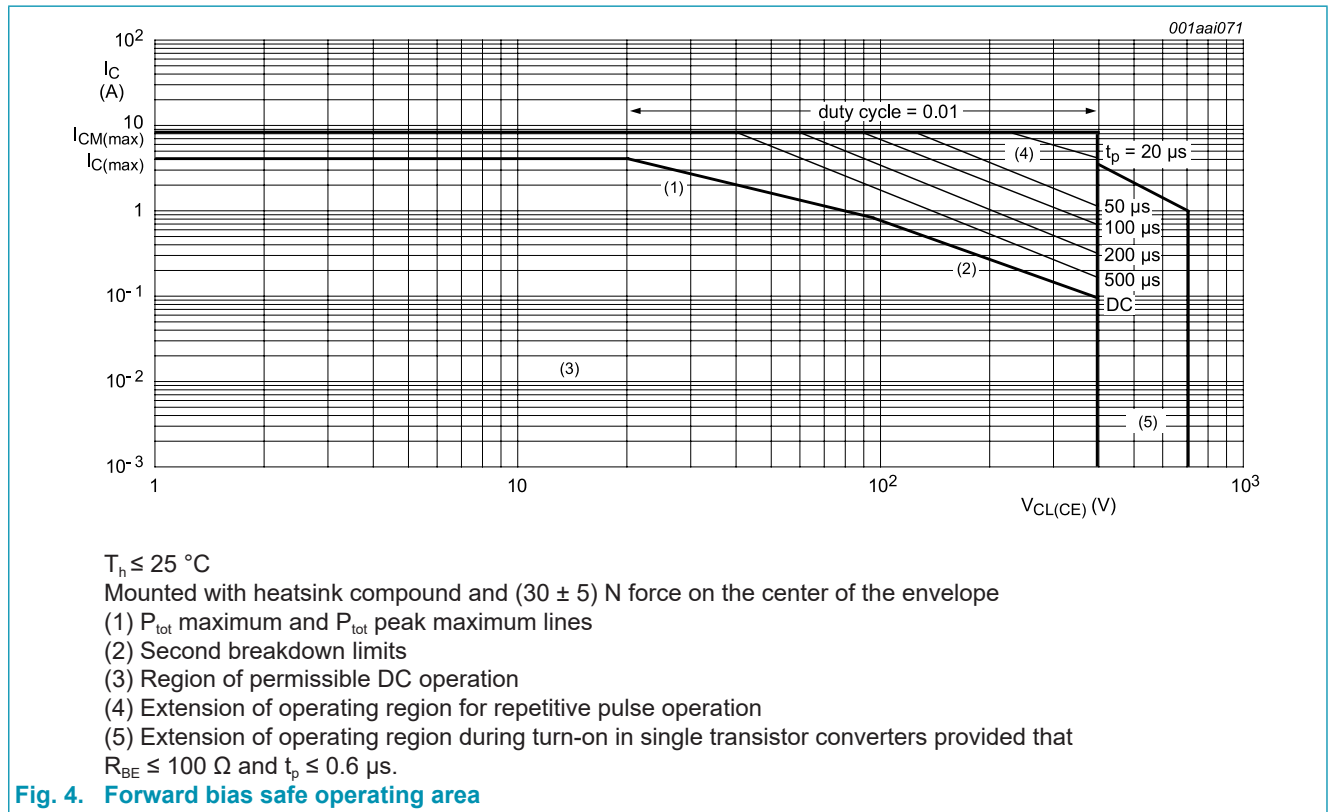
$V_{CL(CE)} \leq 1000 \text{ V}; V_{CC} = 150 \text{ V}; V_{BB} = -5 \text{ V};$   
 $L_B = 1 \text{ } \mu\text{H}; L_C = 200 \text{ } \mu\text{H}.$

Fig. 2. Test circuit for reverse bias safe operating area



$$P_{der}(\%) = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100\%$$

Fig. 3. Normalized total power dissipation as a function of heatsink temperature



### 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 5</a>	-	-	1.67	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W

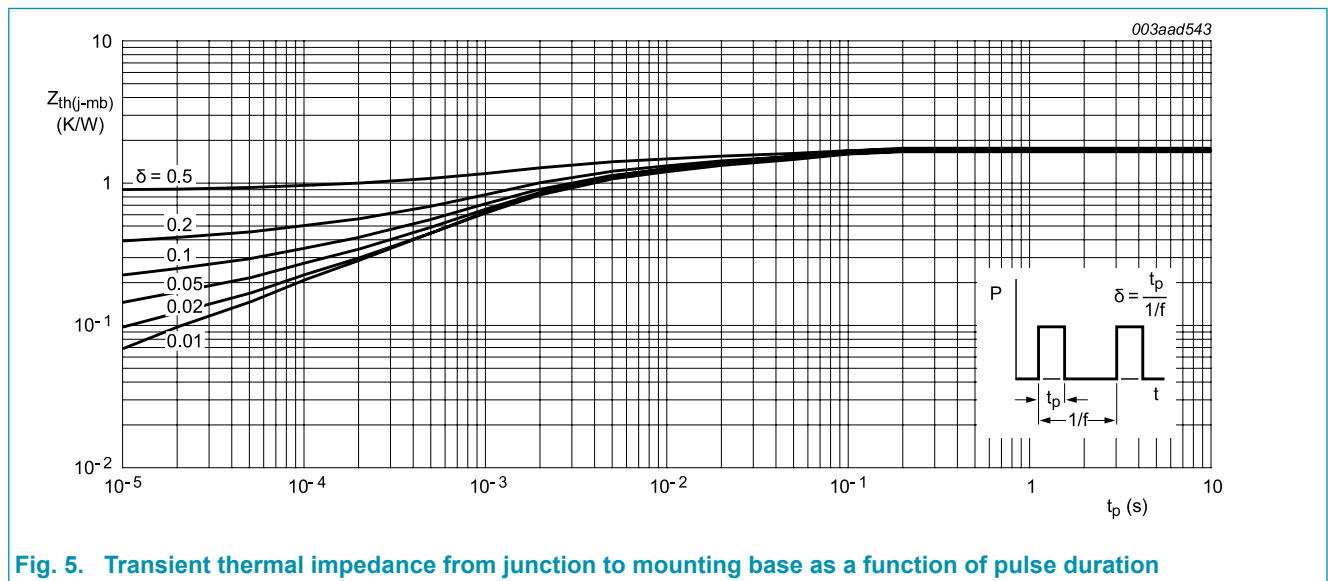


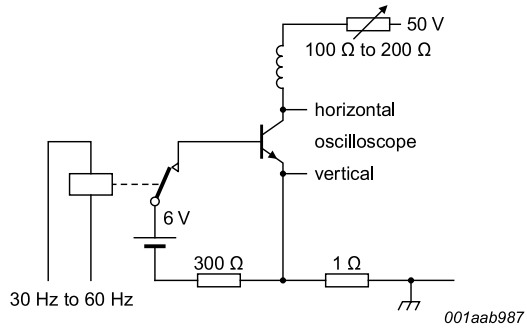
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 9. Characteristics

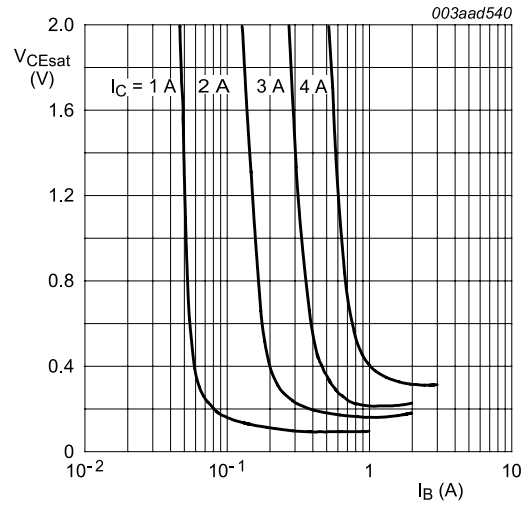
Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{CES}$	collector-emitter cut-off current	$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}; T_j = 100\text{ °C}; [1]$	-	-	5	mA
		$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}; [1]$	-	-	1	mA
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 700\text{ V}; I_E = 0\text{ A}; [1]$	-	-	1	mA
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 400\text{ V}; I_B = 0\text{ A}; [1]$	-	-	0.1	mA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 9\text{ V}; I_C = 0\text{ A}$	-	-	10	mA
$V_{CEOsus}$	collector-emitter sustaining voltage	$I_B = 0\text{ A}; I_C = 10\text{ mA}; L_C = 25\text{ mH};$ <a href="#">Fig. 6; Fig. 15</a>	400	-	-	V
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 1.0\text{ A}; I_B = 0.2\text{ A};$ <a href="#">Fig. 7; Fig. 8</a>	-	0.1	0.5	V
		$I_C = 2.0\text{ A}; I_B = 0.5\text{ A};$ <a href="#">Fig. 7; Fig. 8</a>	-	0.2	0.6	V
		$I_C = 4.0\text{ A}; I_B = 1.0\text{ A};$ <a href="#">Fig. 7; Fig. 8</a>	-	0.3	1	V
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 2.0\text{ A}; I_B = 0.5\text{ A};$ <a href="#">Fig. 9</a>	-	0.92	1.6	V
		$I_C = 1.0\text{ A}; I_B = 0.2\text{ A};$ <a href="#">Fig. 9</a>	-	0.85	1.2	V
$V_F$	forward voltage	$I_F = 2.0\text{ A}$	-	1.04	1.5	V
$h_{FE}$	DC current gain	$I_C = 1.0\text{ A}; V_{CE} = 5\text{ V};$ <a href="#">Fig. 10</a>	12	20	40	
		$I_C = 2.0\text{ A}; V_{CE} = 5\text{ V};$ <a href="#">Fig. 10</a>	10	17	28	
<b>Dynamic characteristics</b>						
$t_s$	storage time	$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; V_{BB} = -5\text{ V};$ $L_B = 1\text{ }\mu\text{H};$ inductive load; <a href="#">Fig. 11;</a> <a href="#">Fig. 12</a>	-	1.2	2	$\mu\text{s}$
		$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; I_{B(off)} = -0.4\text{ A};$ $R_L = 75\text{ }\Omega;$ resistive load; <a href="#">Fig. 13;</a> <a href="#">Fig. 14</a>	-	2.7	4	$\mu\text{s}$
		$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; V_{BB} = -5\text{ V};$ $L_B = 1\text{ }\mu\text{H}; T_j = 100\text{ °C};$ inductive load; <a href="#">Fig. 11; Fig. 12</a>	-	1.4	4	$\mu\text{s}$
$t_f$	fall time	$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; I_{B(off)} = -0.4\text{ A};$ $R_L = 75\text{ }\Omega;$ resistive load; <a href="#">Fig. 13;</a> <a href="#">Fig. 14</a>	-	0.3	0.9	$\mu\text{s}$
		$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; V_{BB} = -5\text{ V};$ $L_B = 1\text{ }\mu\text{H}; T_j = 100\text{ °C};$ inductive load; <a href="#">Fig. 11; Fig. 12</a>	-	0.16	0.9	$\mu\text{s}$
		$I_C = 2.0\text{ A}; I_{B(on)} = 0.4\text{ A}; V_{BB} = -5\text{ V};$ $L_B = 1\text{ }\mu\text{H};$ inductive load; <a href="#">Fig. 11;</a> <a href="#">Fig. 12</a>	-	0.1	0.5	$\mu\text{s}$

[1] Measured with half-sine wave voltage (curve tracer).

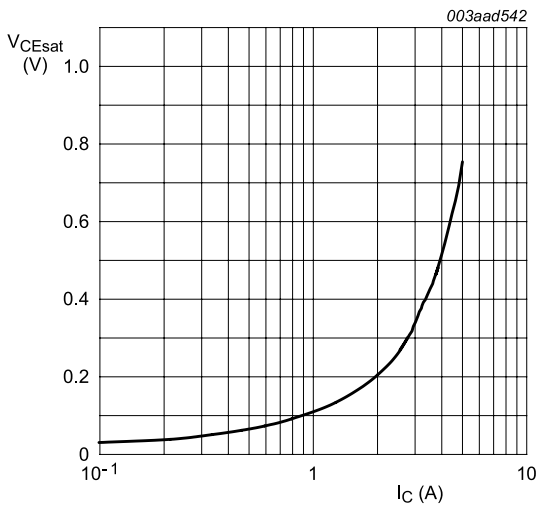


**Fig. 6. Test circuit for collector-emitter sustaining voltage**



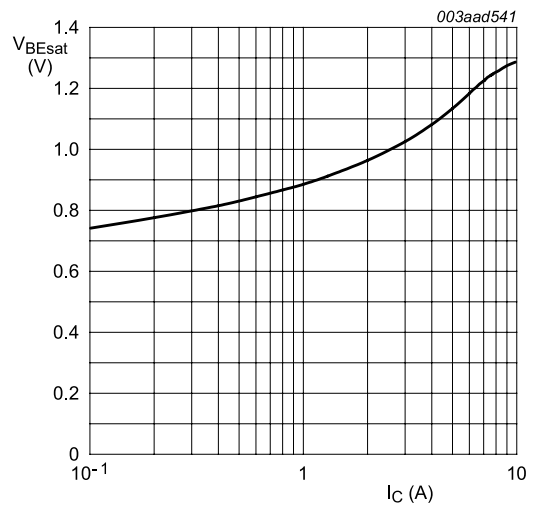
$T_j = 25\text{ }^\circ\text{C}$

**Fig. 7. Collector-emitter saturation voltage; typical values**



$I_C / I_B = 4$

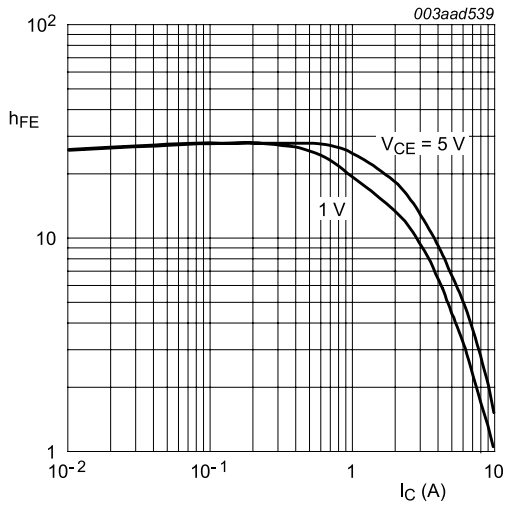
**Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values**



$I_C / I_B = 4$

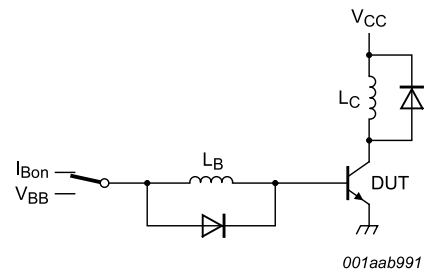
**Fig. 9. Base-emitter saturation voltage; typical values**





$T_j = 25\text{ }^\circ\text{C}$

Fig. 10. DC current gain as a function of collector current; typical values



$V_{CC} = 300\text{ V}; V_{BB} = -5\text{ V}; L_C = 200\text{ }\mu\text{H}; L_B = 1\text{ }\mu\text{H}.$

Fig. 11. Test circuit for inductive load switching

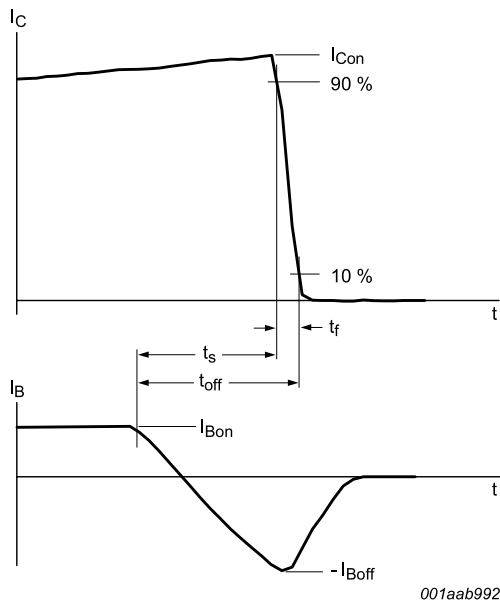
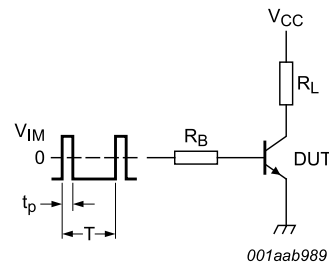


Fig. 12. Switching times waveforms for inductive load



$V_{IM} = -6\text{ V to }+8\text{ V}; V_{CC} = 250\text{ V}; t_p = 20\text{ }\mu\text{s};$   
 $\delta = t_p/T = 0.01.$

$R_B$  and  $R_L$  calculated from  $I_{Con}$  and  $I_{Bon}$  requirements

Fig. 13. Test circuit for resistive load switching

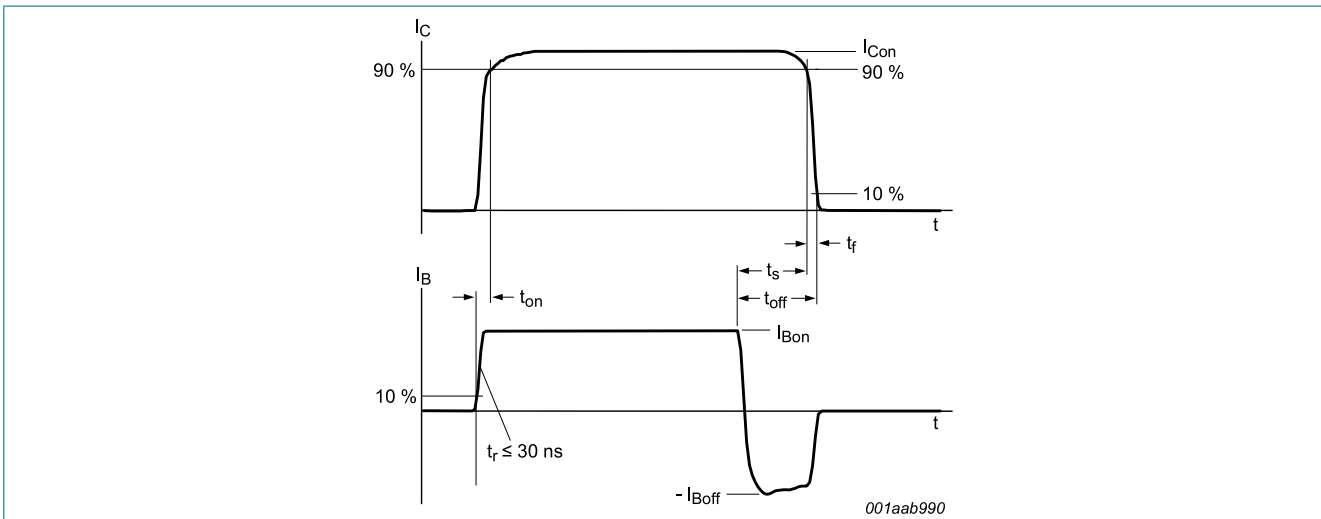


Fig. 14. Switching times waveforms for resistive load

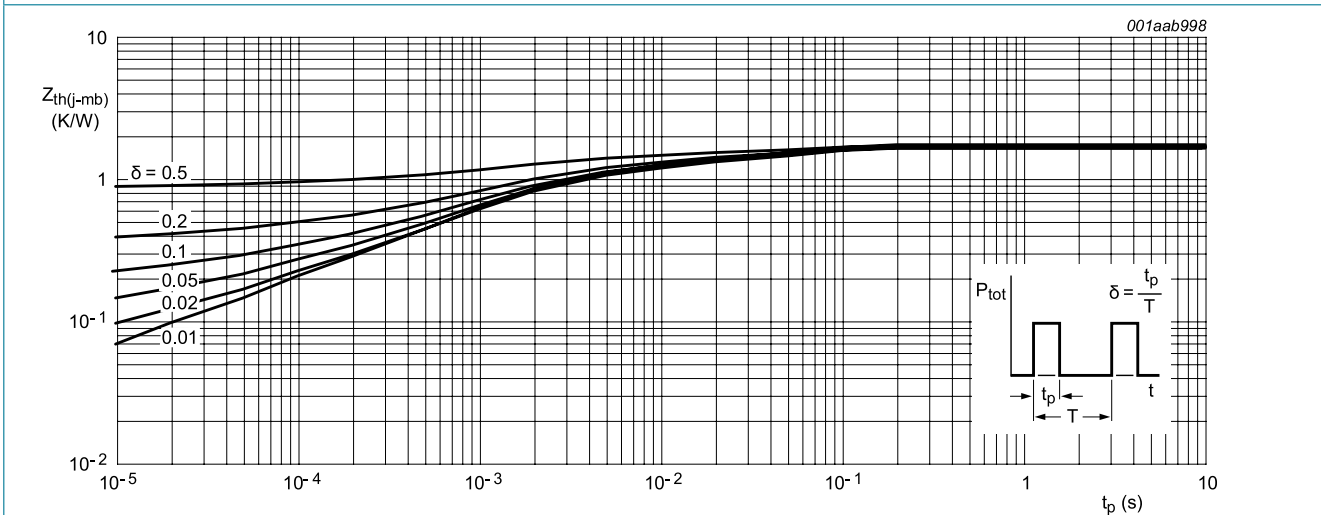
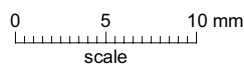
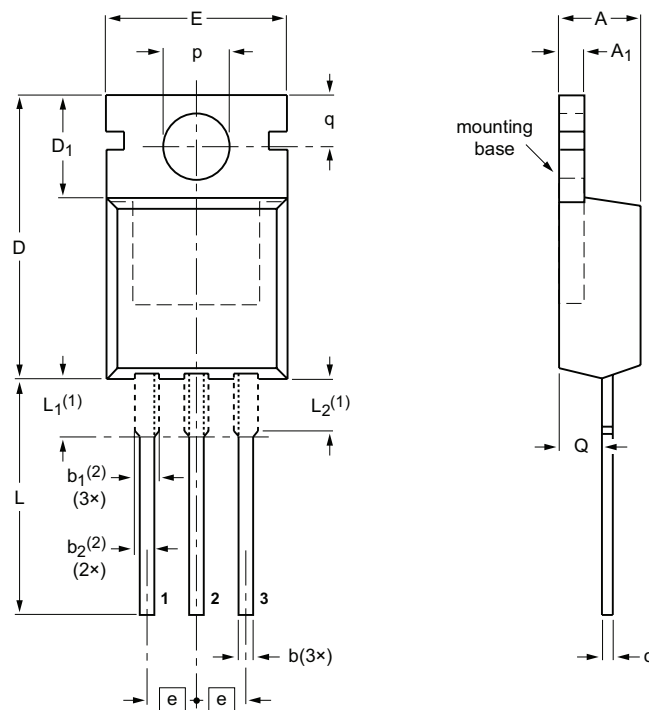


Fig. 15. Transient thermal impedance from junction to mounting base as a function of pulse width

### 10. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



**DIMENSIONS** (mm are the original dimensions)

UNIT	A	A <sub>1</sub>	b	b <sub>1</sub> ( <sup>2</sup> )	b <sub>2</sub> ( <sup>2</sup> )	c	D	D <sub>1</sub>	E	e	L	L <sub>1</sub> ( <sup>1</sup> )	L <sub>2</sub> ( <sup>1</sup> ) max.	p	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

**Notes**

- 1. Lead shoulder designs may vary.
- 2. Dimension includes excess dambar.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT78		3-lead TO-220AB	SC-46		08-04-23 08-06-13

## 11. Revision history

**Table 7. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHD13005 v.3	20180330	Product data sheet	-	PHD13005 v.2
Modifications:	Change from NXP version to WeEn version			
PHD13005 v.2	20100729	Product data sheet	-	PHD13005 v.1
Modifications:	Various changes to content.			
PHD13005 v.1	20100520	Product data sheet	-	-

## 12. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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